

# **Connection Diagrams and Ordering Information**

Ambient Temperature	Туре	Package	Part Number	Packaging Type	Connection Diagram		
-55°C to 125°C	J	16-PIN	SG1548J-883B		LOWER THRESHOLD		
-55 C 10 125 C	Ū	CERAMIC DIP	SG1548J	GERDIF	GERDIP	CERDIP	GROUND 2 15 INV. INPUT V <sub>REF</sub> 3 14 SENSE 4 +V <sub>IN</sub> 4 13 SENSE 3
-25°C to 85°C	N	16-PIN	SG2548N*		LINE SENSE 5 12 SENSE 2 EMITTER OUTPUT 6 11 SENSE 1 COLLECTOR OUTPUT 7 10 U.V. FAULT		
0°C to 70°C		PLASTIC DIP	SG3548N*	PDIP	DELAY		
-25°C to 85°C	DW	16-PIN SMALL-	SG2548DW*	SOWB	LOWER THRESHOLD   1   16   INV. OUTPUT     GROUND   2   15   INV. INPUT $V_{REF}$ 3   14   SENSE 4 $+V_{N}$ 4   13   SENSE 3     LINE SENSE   5   12   SENSE 2		
0°C to 70°C		OUTLINE WIDE BODY	SG3548DW*		EMITTER OUTPUT   6   11   SENSE 1     COLLECTOR OUTPUT   7   10   U.V. FAULT     DELAY   8   9   O.V. FAULT     DW package:   Pb-free / RoHS   100% Matte Tin Lead Finish		
-55°C to 125°C	L	20-PIN CERAMIC	SG1548L-883B	CLCC	1. N.C.     3     2     1     20     19     11. N.C.       2. LOWER THRESHOLD     3     6     12. O.V. FAULT     12. O.V. FAULT       3. GROUND     4     13. U.V. FAULT     18. SENSE 1     13. U.V. FAULT       5. +V.     6     6     17. 15. SENSE 2     16. N.C.       7. LINE SENSE     1     16. N.C.     17. SENSE 3		
		(LCC)	SG1548L		7. LINE SERVE     7       8. EMITTER OUTPUT     8       9. COLLECTOR     11       0UTPUT     9       10. DELAY     9		
Notes:		mus desset assails	.h:1:4.				

1. Contact factory for DESC product availability.

All parts are viewed from the top.
Hermetic Packages J & L use Pb37/Sn63 hot solder lead finish, contact factory for availability of RoHS versions.

\*RoHS Compliant



# Absolute Maximum Ratings<sup>1</sup>

Parameter	Value	Units
Supply Voltage (+V <sub>IN</sub> )	40	V
Fault Output Collector Voltage	40	V
Sense Input Voltage Range	-0.3V to 6.0V	V
Fault Output Sink Current	20	mA
Line Sense Input Current	±1	mA
Inverting Op Amp Input Current	-5	mA
Inverting Op Amp Output Current	25	mA
Operating Junction Temperature		
Hermetic (J, L Packages)	150	°C
Plastic (N, DW Packages)	150	°C
Storage Temperature Range	-65 to 150	°C
Lead Temperature	300	°C
<i>Notes:</i> 1. Values beyond which damage may occur.		

2. Pb-free / RoHS Peak Package Solder Reflow Temp. (40 second max. exposure). 260°C (+0, -5)

## **Thermal Data**

Parameter	Value	Units
J Package		
Thermal Resistance-Junction to Case, $\theta_{\text{JC}}$	30	°C/W
Thermal Resistance-Junction to Ambient, $\theta_{JA}$	80	°C/W
N Package		
Thermal Resistance-Junction to Case, $\theta_{\text{JC}}$	40	°C/W
Thermal Resistance-Junction to Ambient, $\theta_{JA}$	65	°C/W
DW Package		
Thermal Resistance-Junction to Case, $\theta_{\text{JC}}$	40	°C/W
Thermal Resistance-Junction to Ambient, $\theta_{JA}$	95	°C/W
L Package		
Thermal Resistance-Junction to Case, $\theta_{\text{JC}}$	35	°C/W
Thermal Resistance-Junction to Ambient, $\theta_{JA}$	120	°C/W
Notes:		-

1. Junction Temperature Calculation:  $T_J = T_A + (P_D \times \theta_{JA})$ .

2. The above numbers for  $\theta_{JC}$  are maximums for the limiting thermal resistance of the package in a standard mounting configuration. The  $\theta_{JA}$  numbers are meant to be guidelines for the thermal performance of the device/pc-board system. All of the above assume no ambient airflow.



# Recommended Operating Conditions<sup>1</sup>

Supply Voltage Range	Value	Units
±25% Maximum Fault Window <sup>(2)</sup>	4.5 to 35	V
±40% Maximum Fault Window	5.0 to 35	V
Lower Threshold Input Range	1.5 to 2.45	V
Fault Tolerance Window Range	±5 to ±40	%
Fault Output Sink Current Range	0 to 10	mA
Line Sense Output Current Range	0 to 10	mA
Voltage Reference Output Current	0 to 10	mA
Operating Ambient Temperature Range		
SG1548	-55 to 125	°C
SG2548	-25 to 85	°C
SG3548	0 to 70	°C
<i>Notes:</i> 1. Range over which the device is functional.		

2. Limited by inverter amplifier positive swing at -55°C.

## **Electrical Characteristics**

Unless otherwise specified, these specifications apply over the operating ambient temperatures for SG1548 with -55°C  $\leq T_A \leq 125$ °C, SG2548 with -25°C  $\leq T_A \leq 85$ °C, SG3548 with 0°C  $\leq T_A \leq 70$ °C, and +V<sub>IN</sub> = 15V. Low duty cycle pulse testing techniques are used which maintains junction and case temperatures equal to the ambient temperature.

Parameter			SG1548/2548		SG3548		Units	
		Min	Тур	Max	Min	Тур	Max	
Supply Section			-					
Supply Current	$+V_{IN} = 40V$		4.8	10		4.8	10	mA
Reference Section <sup>(1)</sup>								
Output Voltage	T <sub>J</sub> = 25°C	2.475	2.500	2.525	2.475	2.500	2.525	V
	Over Temperature	2.450		2.550	2.450		2.550	V
Line Regulation	$+V_{IN} = 4.5V$ to 35V		1	5		1	5	mV
Load Regulation	$I_L = 0$ to 10mA		3	10		3	10	mV
Short Circuit Current	$V_{REF} = 0V$	10	25	50	10	25	50	mA
Fault Window Generator Section	on	•					•	
Input Bias Current	V <sub>PIN 1</sub> = 1.5V to 2.45V		-0.4	-2.0		-0.4	-2.0	μA
DC Sense Inputs Section	· ·	•					•	
Overvoltage Threshold	$V_{PIN 1} = 0.95 \times V_{REF}$	2.547	2.625	2.704	2.547	2.625	2.704	V
-	V <sub>PIN 1</sub> = 0.60 x V <sub>REF</sub>	3.396	3.500	3.606	3.396	3.500	3.606	V
Undervoltage Threshold	V <sub>PIN 1</sub> = 0.95 x V <sub>REF</sub>		2.375		2.304	2.375	2.447	V
	V <sub>PIN 1</sub> = 0.60 x V <sub>REF</sub>	1.455	1.500	1.545	1.455	1.500	1.545	V
Input Bias Current	V <sub>SENSE</sub> = 1.5V to 3.5V		±0.6	±2.0		±0.6	±2.0	μA
Threshold Supply Rejection	$+V_{IN} = 4.5V \text{ to } 35V$	60	100		60 100			dB
Fault Delay Section			1	11			1	
Comparator Threshold		1.200	1.250	1.300	1.200	1.25	0 1.300	V
Comparator Hysteresis			25		25			mV
Delay Charging Current	V <sub>PIN 8</sub> = 0V	32.5	50	67.5	32.5 50		67.5	μA
On Saturation Voltage	I PIN 8 = OmA		0.1	0.2	0.1			V
OFF Clamp Voltage	I <sub>PIN 8</sub> = 0mA		+3.2	+3.6	+3.2			V
Inverting Op Amp Section <sup>(2)</sup>				1 1				
Input Offset Voltage			2	15		2	15	mV
Input Bias Current			-0.3	-1.0		-0.3	-1.0	μA
Output High Voltage	I <sub>SOURCE</sub> = 5mA	3.2	3.5	_	3.2	3.5	-	V
Output Low Voltage	I <sub>SINK</sub> = 5mA	-	1.0	1.9	-	1.0	1.9	V
Large Signal Voltage Gain	$R_L = 10k$	72	100	_	72	100	-	dB
Output Source Current		5	15	25	5	15	25	mA
Power Supply Rejection Ratio	$+V_{IN} = 4.5V$ to 35V	72	100	_	72	100	-	dB
AC Line Sense Section				1				
Comparator Threshold	V <sub>PIN5</sub> = Low to High	2.440	2.500	2.560	2.440	2.500	2.560	V
Comparator Hysteresis			25		-	25		mV
Input Bias Current	V <sub>PIN 5</sub> = 2.5V		1	2		1	2	μA
Collector Leakage Current	$V_{CE} = 40V$		1	10			10	μΑ
Collector Saturation Voltage	$I_{C}=10$ mA		0.2	0.5		0.2		ν ν
Emitter Output Voltage	$I_E = 10 \text{mA}$	12	13	0.0	12	13	0.5	V
Diode Clamp Voltage	$I_{PIN 5} = 1 \text{mA}$	6.0	.0	7.5	6.0		7.5	V
	$I_{PIN5} = -1mA$	-0.3		-1.0			-1.0	V
Fault Logic Outputs (Each out		0.0	1	1.0	0.0	1	1.0	v
Collector Leakage Current	$V_{\rm C} = 40V$		1	10			1 10	μA
Collector Saturation Voltage	$I_c = 10 \text{mA}$		0.2	0.5			.2 0.5	V
Concolor Caluration vollage			0.2	0.5		0	0.3	v

1.  $I_L = 0mA$ 2.  $+V_{IN} = 4.5V$ .



## **Application Information**

### **Setting the Fault Tolerance Window**

The fault tolerance window is set by applying a voltage less than the +2.50Vreference to the Lower Threshold input (Pin 1). The voltage is obtained by a resistor divider from the reference (Pin 3) to ground. If  $\pm 5\%$  tolerance is desired, then 95% of the reference (+2.375V) is applied to Pin 1. If  $\pm 40\%$  is wanted, then 60% of the reference (+1.50V) is applied. In the example on the back page, the tolerance is  $\pm 5\%$ . The nominal overvoltage and undervoltage thresholds are centered about the reference at +2.625V and +2.375V (+2.500V  $\pm 0.125V$ ).

### Scaling the Monitored Supply Voltages

Each positive voltage to be monitored is divided down to  $\pm 2.50V$  with a resistor network and connected to one of the Sense inputs. Unused Sense inputs should be connected to the reference. This will not increase the bias current. A variation of the monitored voltages out of the programmed tolerance range will cause the appropriate overvoltage or undervoltage fault output to switch LOW. The effective tolerance on any input may be broadened with an additional resistor to the voltage reference. The example on the back page shows a  $\pm 10\%$  tolerance on the  $\pm 5V$  supply although the SG1548 is programmed for a  $\pm 5\%$  tolerance. The procedure for calculating the resistor value is found in the SG1548 Application Note.

### **Monitoring a Negative Voltage**

A negative voltage can be converted to a positive one and simultaneously scaled to +2.50V by using the internal operational amplifier as an inverter. Only an input resistor and feedback resistor are required.

### **Setting the Fault Delay**

A single capacitor at the Delay pin sets the time an out-of tolerance fault must persist before a fault is actually declared. This feature allows switching noise on the supplies to be rejected. The delay time is given by: Delay =  $25ms/\mu F$ .

#### **AC Line Monitoring**

The AC line voltage can be monitored for single-cycle dropouts with the few components shown in the example. A half-wave rectifier charges the capacitor on positive line cycles. After the positive peak and during the negative line cycle the capacitor discharges from a fixed voltage controlled by the internal Zener diode. If a positive cycle is missing, the capacitor discharges to below the +2.5V trip point of the comparator, causing the output transistor to turn on.



### **Application Example**

In this example, the SG1548 simultaneously monitors four DC voltages: +5V, +24V, and ±15V. Three different fault tolerances are programmed:  $\pm 5\%$  on the two 15V supplies,  $\pm 10\%$  on the +5V supply, and  $\pm 20\%$  on the +24V supply. The 5µF delay capacitor provides 125 milliseconds of fault delay.

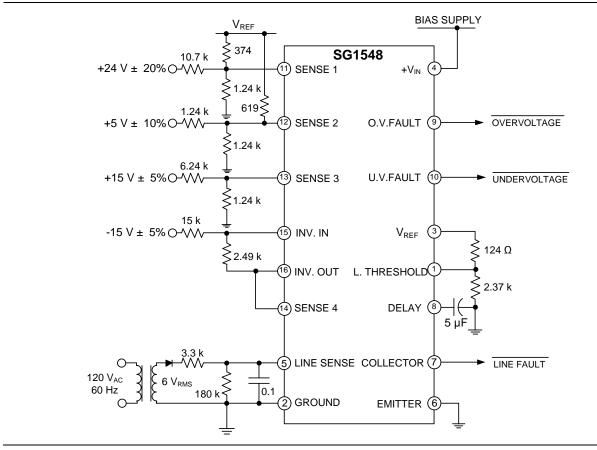
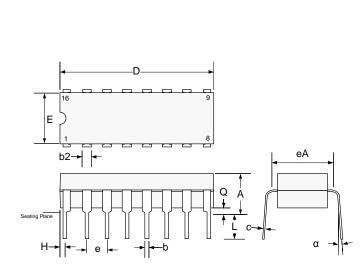


Figure 2 - Application Example



## Package Outline Dimensions

Controlling dimensions are in inches, metric equivalents are shown for general information.

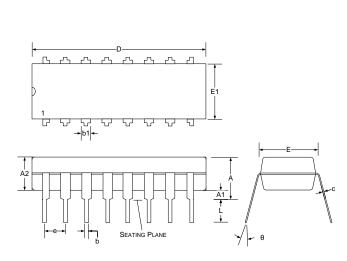


Dim	MILLIN	IETERS	INCHES		
Dim	MIN	MAX	MIN	MAX	
А		5.08		0.200	
b	0.38	0.51	0.015	0.020	
b2	1.04	1.65	0.045	0.065	
С	0.20	0.38	0.008	0.015	
D	19.30	19.94	0.760	0.785	
Е	5.59	7.11	0.220	0.280	
е	2.54	BSC	0.100 BSC		
eA	7.37	7.87	0.290	0.310	
Н	0.63	1.78	0.025	0.070	
L	3.18	5.08	0.125	0.200	
α	-	15°	-	15°	
Q	0.51	1.02	0.020	0.040	

#### Note:

Dimensions do not include protrusions; these shall not exceed 0.155mm (.006") on any side. Lead dimension shall not include solder coverage.

Figure 3 - J 16-Pin Ceramic Dip



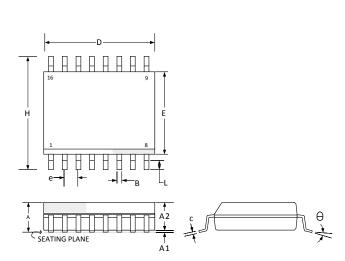
Dim	MILLIM	ETERS	INCHES		
Dim	MIN	MAX	MIN	MAX	
А		5.33		0.210	
A1	0.38		0.015		
A2	3.30	Тур.	0.13	0 Тур.	
b	0.36	0.56	0.014	0.022	
b1	1.14	1.78	0.045	0.070	
С	0.20	0.36	0.008	0.014	
D	18.67	19.69	0.735	0.775	
е	2.54	BSC	0.100	) BSC	
Е	7.62	8.26	0.300	0.325	
E1	6.10	7.11	0.240	0.280	
L	2.92	0.381	0.115	0.150	
θ	-	15°	-	15°	

#### Note:

Dimensions do not include mold flash or protrusions; these shall not exceed 0.155mm (.006") on any side. Lead dimension shall not include solder coverage.

## Package Outline Dimensions (continued)

Controlling dimensions are in inches, metric equivalents are shown for general information.



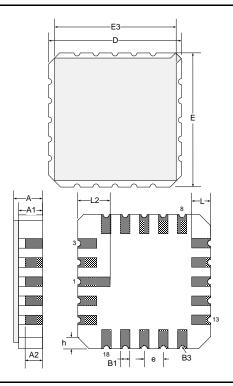
Dim	MILLIN	IETERS	INCHES		
Dim	MIN	MAX	MIN	MAX	
Α	2.06	2.65	0.081	0.104	
A1	0.10	0.30	0.004	0.012	
A2	2.03	2.55	0.080	0.100	
В	0.33	0.51	0.013	0.020	
С	0.23	0.32	0.009	0.013	
D	10.08	10.50	0.397	0.413	
E	7.40	7.60	0.291	0.299	
е	1.27	1.27 BSC		BSC	
Н	10.00	10.65	0.394	0.419	
L	0.40	1.27	0.016	0.050	
Θ	0°	8°	0°	8°	
*LC	_	0.10	-	0.004	

#### Note:

1. Controlled dimensions are in mm, inches are for reference only.

2. Dimensions do not include mold flash or protrusions; these shall not exceed 0.155mm (.006") on any side. Lead dimension shall not include solder coverage.

Figure 12 - DW 16-Pin Plastic Wide-body SOIC



Dim	MILLIN	IETERS	INCHES		
Dim	MIN	MAX	MIN	MAX	
D/E	8.64	9.14	0.340	0.360	
E3	-	8.128	-	0.320	
е	1.270	BSC	0.050 BSC		
B1	0.635	0.635 TYP		5 TYP	
L	1.02	1.52	0.040	0.060	
А	1.626	2.286	0.064	0.090	
h	1.016	S TYP	0.040	) TYP	
A1	1.372	1.68	0.054	0.066	
A2	-	1.168	-	0.046	
L2	1.91	2.41	0.075	0.95	
B3	0.20	03R	0.008R		

#### Note:

All exposed metalized area shall be gold plated 60 micro-inch minimum thickness over nickel plated unless otherwise specified in purchase order.





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